Unit: mm

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type ($L^2-\pi$ -MOSV)

2SJ438

DC-DC Converter, Relay Drive and Motor Drive Applications

• 4 V gate drive

• Low drain-source ON resistance : $RDS (ON) = 0.16 \Omega (typ.)$ • High forward transfer admittance : $|Y_{fs}| = 4.0 S (typ.)$

• Low leakage current $: I_{DSS} = -100 \,\mu\text{A} \,(\text{max}) \,(V_{DS} = -60 \,\text{V})$

• Enhancement-mode : $V_{th} = -0.8 \sim -2.0 \text{ V (V}_{DS} = -10 \text{ V, I}_{D} = -1 \text{ mA})$

Maximum Ratings (Ta = 25°C)

Characteris	stics	Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	-60	V	
Drain-gate voltage (Ro	_{SS} = 20 kΩ)	V_{DGR}	-60	V	
Gate-source voltage		V _{GSS}	±20	V	
Drain current	DC (Note 1)	I _D	-5	Α	
Diam current	Pulse(Note 1)	I _{DP}	-20	Α	
Drain power dissipation	n (Tc = 25°C)	P_{D}	25	W	
Single pulse avalanche	e energy (Note 2)	E _{AS}	273	mJ	
Avalanche current		I _{AR}	-5	Α	
Repetitive avalenche e	nergy (Note 3)	E _{AR}	2	mJ	
Channel temperature		T _{ch}	150	°C	
Storage temperature ra	ange	T _{stg}	-55~150	°C	

2-10R1B

Weight: 1.9 g (typ.)

TOSHIBA

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	5.0	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	62.5	°C/W

Note 1: Please use devices on condition that the channel temperature is below 150°C.

Note 2: V_{DD} = -25 V, T_{ch} = 25°C (initial), L = 14.84 mH, R_G = 25 Ω , I_{AR} = -5 A

Note 3: Repetitive rating; Pulse width limited by maximum channel temperature.

This transistor is an electrostatic sensitive device.

Please handle with caution.

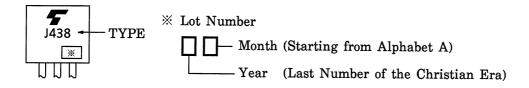
Electrical Characteristics (Ta = 25°C)

Charac	eteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	ırrent	I_{GSS}	V _{GS} = ±16 V, V _{DS} = 0 V	_	_	±10	μΑ
Drain cut-off cu	rrent	I _{DSS}	V _{DS} = -60 V, V _{GS} = 0 V	_	_	-100	μA
Drain-source br	eakdown voltage	V _{(BR) DSS}	$I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$	-60	_	_	٧
Gate threshold v	oltage	V_{th}	$V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA}$	-0.8	_	-2.0	٧
Drain-source ON resistance		R _{DS (ON)}	$V_{GS} = -4 \text{ V}, I_D = -2.5 \text{ A}$	_	0.24	0.28	Ω
			$V_{GS} = -10 \text{ V}, I_D = -2.5 \text{ A}$	_	0.16	0.19	
Forward transfe	r admittance	Y _{fS}	V _{DS} = -10 V, I _D = -2.5 A	2.0	4.0	_	S
Input capacitano	e	C _{iss}		_	630	_	pF
Reverse transfe	r capacitance	C _{rss}	V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz	_	95	_	
Output capacitance		Coss]	_	290	_	
Switching time	Rise time	t _r	$V_{GS} \stackrel{OV}{\longrightarrow} I_{D} = -2.5A$ $V_{CS} \stackrel{OV}{\longrightarrow} I_{D} = -2.5A$ $R_{L} = 12\Omega$ $V_{DD} = -30V$	_	25	_	ns
	Turn-on time	t _{on}		_	45	_	
	Fall time	t _f		_	55		
	Turn-off time	t _{off}	Duty $\leq 1\%$, $t_{\mathbf{W}} = 10 \mu \text{s}$	_	200	_	
Total gate charge (Gate-source plus gate-drain)		Qg	$V_{DD} \approx -48 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -5 \text{ A}$	_	22	_	nC
Gate-source charge		Q _{gs}		_	16	_	
Gate-drain ("miller") charge		Q _{gd}			6	_	

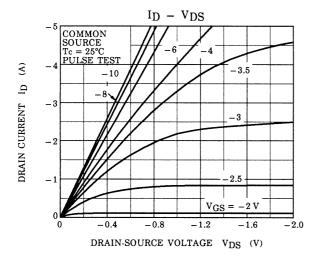
Source-Drain Ratings and Characteristics (Ta = 25°C)

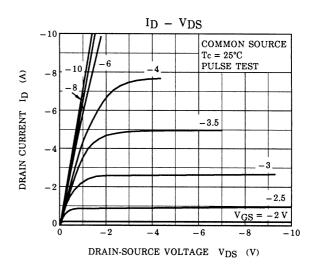
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	_	_	_	-5	Α
Pulse drain reverse current (Note 1)	I _{DRP}		_	-	-20	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = -5 A, V _{GS} = 0 V	_	_	1.7	V
Reverse recovery time	t _{rr}	$I_{DR} = -5 \text{ A}, V_{GS} = 0 \text{ V } dI_{DR} / dt = 50 \text{ A} / \mu \text{s}$	_	80	_	ns
Reverse recovery charge	Q_{rr}		_	0.1	_	μC

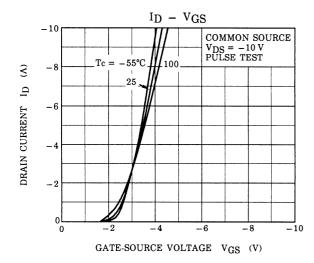
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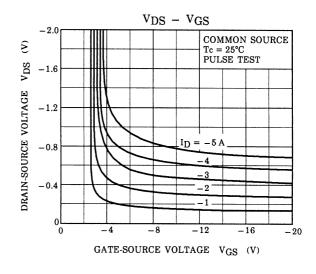


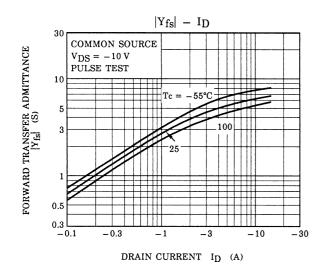
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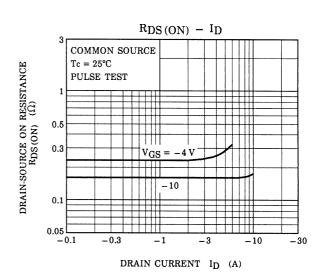




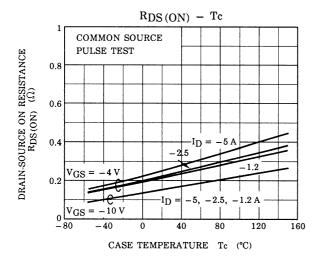


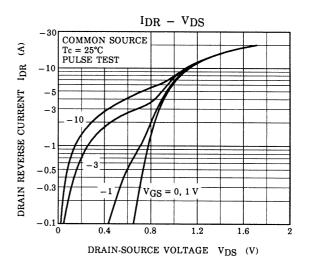


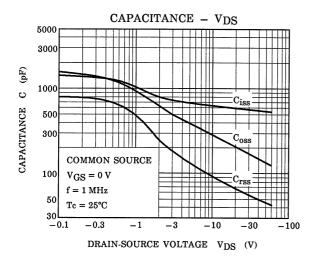


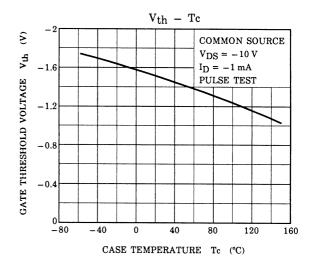


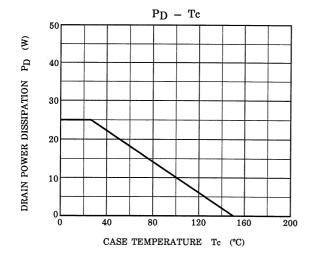
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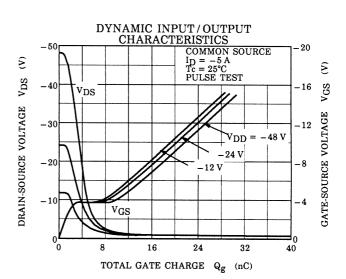




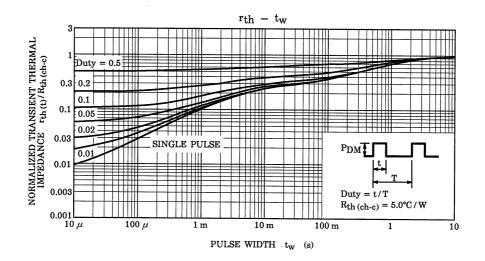


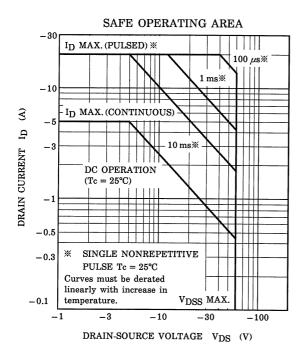


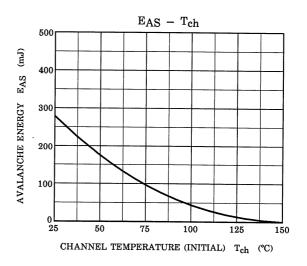


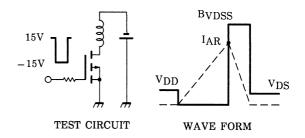


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$$\begin{array}{ll} R_G\!=\!25\Omega \\ V_{DD}\!=\!-25V,\; L\!=\!14.84mH \end{array} \quad E_{AS}\!=\!\frac{1}{2}\cdot L\cdot I^2\cdot (\frac{B_{VDSS}}{B_{VDSS}\!-\!V_{DD}})$$

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